

# SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

## LV8402GP - <sup>Bi-CMOS IC</sup> 2ch Forward/Reverse Motor Driver

## Overview

LV8402GP is a 2ch forward/reverse motor driver IC using D-MOS FET for output stage. As MOS circuit is used, it supports the PWM input. Its features are that the on resistance  $(0.75\Omega \text{ typ})$  and current dissipation are low. It also provides protection functions such as heat protection circuit and reduced voltage detection and is optimal for the motors that need high-current.

## **Functions**

- 2ch forward/reverse motor driver.
- Low power consumption.
- Low ON resistance 0.75Ω.

- Built-in low voltage reset and thermal shutdown circuit.
- 4 mode function forward/reverse, brake and standby.
- Built-in charge pump.
- Built-in EXTRA mode for PWM port reduction when a motor drives by two phase excitation.

## Specifications

#### Maximum Ratings at Ta = 25°C, SGND = PGND = 0V

| Parameter                          | Symbol              | Conditions                    | Ratings                      | Unit |
|------------------------------------|---------------------|-------------------------------|------------------------------|------|
| Power supply voltage (for load)    | VM max              |                               | -0.5 to 16.0                 | V    |
| Power supply voltage (for control) | V <sub>CC</sub> max |                               | -0.5 to 6.0                  | V    |
| Output current                     | I <sub>O</sub> max  |                               | 1.4                          | А    |
| Output peak current                | I <sub>O</sub> peak | t ≤ 10ms                      | 2.5                          | А    |
| Input voltage                      | V <sub>IN</sub> max |                               | -0.5 to V <sub>CC</sub> +0.5 | V    |
| Allowable power dissipation        | Pd max              | Mounted on a specified board* | 1050                         | mW   |
| Operating temperature              | Topr                |                               | -30 to +85                   | °C   |
| Storage temperature                | Tstg                |                               | -55 to +150                  | °C   |

\* Specified board: 40.0mm  $\times$  50.0mm  $\times$  0.8mm, 4 Layer glass epoxy board.

Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

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#### Allowable Operating Conditions at Ta = 25°C, SGND = PGND = 0V

| Parameter                                  | Symbol | Conditions | Ratings              | Unit |
|--|--------|------------|----------------------|------|
| Power supply voltage (VM pin)              | VM     |            | 1.5 to 15.0          | V    |
| Power supply voltage (V <sub>CC</sub> pin) | VCC    |            | 2.8 to 5.5           | V    |
| Input signal voltage                       | VIN    |            | 0 to V <sub>CC</sub> | V    |
| Input signal frequency                     | f max  |            | 200                  | kHz  |

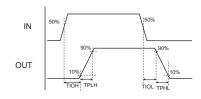
#### **Electrical Characteristics** Ta = $25^{\circ}$ C, V<sub>CC</sub> = 3.0V, VM = 6.0V, SGND = PGND = 0V, unless otherwise specified.

| Parameter   |   | Cumhal            | Quartitions   |         | Ratings             |      |                     | 11   |  |
|---|---|-------------------|---|---------|---------------------|------|---------------------|------|--|
| Para  | meter   | Symbol            | Conditions  | Remarks | min                 | typ  | max                 | Unit |  |
| Standby load cu   | y load current drain IMO EN1=EN2=0V, EXTRA=3V |                   | 1   |         |                     | 1.0  | μΑ                  |      |  |
| Standby control   | current drain                                 | ICO               | EN1=EN2=IN1=IN2=IN3=IN4=0V  | 2       |                     |      | 1.0                 | μΑ   |  |
| Operating contro  | ol current drain                              | IC1               | EN=3V, with no load   | 3       |                     | 0.85 | 1.2                 | mA   |  |
| High-level input  | voltage                                       | VIH               | $2.7 \le V_{CC} \le 5.5V$   |         | 0.6×V <sub>CC</sub> |      | VCC                 | V    |  |
| Low-level input   | voltage                                       | VIL               | $2.7 \le V_{CC} \le 5.5 V$  |         | 0                   |      | 0.2×V <sub>CC</sub> | V    |  |
| High-level input<br>(IN1, IN2 , IN3 ,                           |   | Ιн                | V <sub>IN</sub> = 3V  | 4       |                     | 15   | 25                  | μΑ   |  |
| Low-level input of (IN1, IN2, IN3, I                            |   | ۱                 | V <sub>IN</sub> = 0V  | 4       | -1.0                |      |                     | μΑ   |  |
| Pull-down resista   | ance value                                    | RDN               | IN1, IN2, IN3 , IN4 , EN1, EN2                                    | 4       | 100                 | 200  | 400                 | kΩ   |  |
| High-level input current 2<br>(IN1, IN2 , IN3 , IN4 , EN1, EN2) |   | I <sub>IH</sub> 2 | V <sub>IN</sub> = 3V  | 5       |                     |      | 1.0                 | μΑ   |  |
| Low-level input current 2<br>(IN1, IN2, IN3, IN4, EN1, EN2)     |   | I <sub>IL</sub> 2 | V <sub>IN</sub> = 0V  | 5       | -25                 | -15  |                     | μΑ   |  |
| Pull-up resistance value  |   | RUP               | EXTRA   | 5       | 100                 | 200  | 400                 | kΩ   |  |
| Charge pump vo  | Charge pump voltage                           |                   | V <sub>CC</sub> + VM  |         | 8.5                 | 9.0  | 9.5                 | V    |  |
| Output ON resistance 1  |   | RON1              | Sum of top and bottom sides ON resistance.                        | 6       |                     | 0.75 | 1.2                 | Ω    |  |
| Output ON resistance 2  |   | RON2              | Sum of top and bottom sides ON resistance. V <sub>CC</sub> = 2.8V | 6       |                     | 1.0  | 1.5                 | Ω    |  |
| Low-voltage detection voltage                                   |   | VCS               | V <sub>CC</sub> pin voltage is monitored                          | 7       | 2.15                | 2.30 | 2.45                | V    |  |
| Thermal shutdov   | wn temperature                                | Tth               | Design guarantee value *  | 8       | 150                 | 180  | 210                 | °C   |  |
| Output block  | Turn-on time                                  | TPLH              | When no load. Design guarantee value *                            | 9       |                     | 0.3  | 0.5                 | μS   |  |
|   |   |                   | When no load.   | 10      |                     | 100  | 200                 | nS   |  |
|   | Turn-off time                                 | TPHL              | When no load. Design guarantee value *                            | 9       |                     | 0.35 | 0.6                 | μS   |  |
|   |   |                   | When no load.   | 10      |                     | 100  | 200                 | nS   |  |

\* : Design guarantee value and no measurement is preformed.

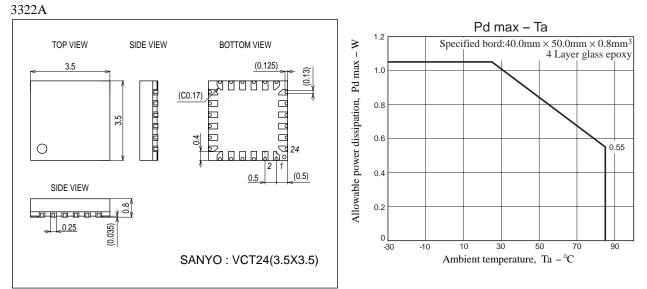
#### Remarks

- 1. Current consumption when output at the VM pin is off.
- 2. Current consumption at the  $V_{CC}$  for standby mode.
- 3. EN1=3V (IC starts) shows the current consumption of the  $V_{CC}$  pin.
- 4. Pins IN 1, 2, 3, 4, EN1, and EN2 are all pulled down according to resistance.
- 5. EXTRA pin is pulled up according to resistance.
- 6. Sum of upper and lower saturation voltages of OUT pin divided by the current.
- 7. All power transistors are turned off if a low  $V_{CC}$  condition is detected.
- 8. All output transistors are turned off if the thermal protection circuit is activated. They are turned on again as the temperature goes down.
- 9. Rising time from 10 to 90% and falling time from 90 to 10% are specified.
- 10. The change of the voltage of the input pin provides for time until the voltage of the terminal OUT changes by 10% at the time of 50% of  $V_{CC}$ .

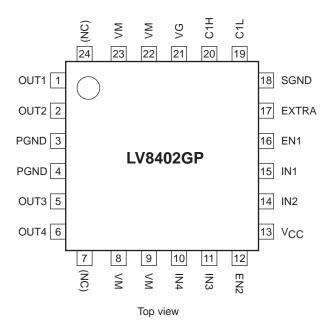


## Package Dimensions

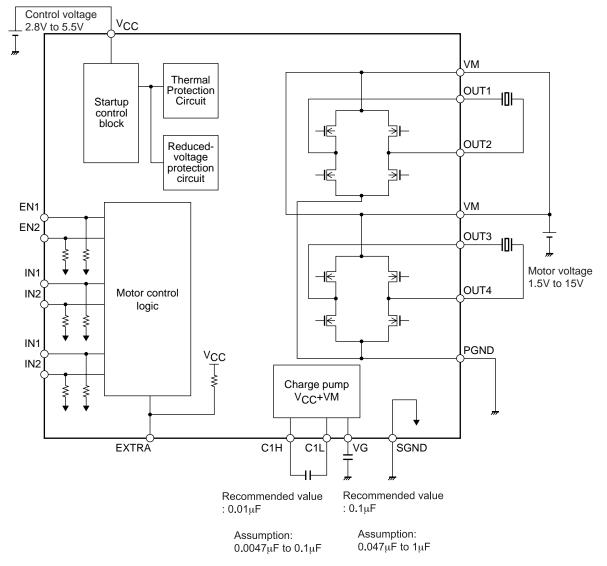
unit : mm (typ)



## **Pin Assignment**



## **Block Diagram**



\* Connect a kickback absorption capacitor as near as possible to the IC. Coil kickback may cause increase in VM line voltage, and a voltage exceeding the maximum rating may be applied momentarily to the IC, which results in deterioration or damage of the IC

### Truth Table

| EXTRA | EN1<br>(EN2) | IN1<br>(IN3) | IN2<br>(IN4) | OUT1<br>(OUT3) | OUT2<br>(OUT4) | Charge pump | Mode     |
|-------|--------------|--------------|--------------|----------------|----------------|-------------|----------|
| н     | н            | н            | н            | Z              | Z              | ON          | Stand-by |
|       |              | Н            | L            | L              | н              |             | Reverse  |
|       |              | L            | Н            | Н              | L              |             | Forward  |
|       |              | L            | L            | L              | L              |             | Brake    |
|       | L            | -            | -            | L              | L              | OFF         | Stand-by |
| L     | н            | н            | -            | L              | н              | ON          | Reverse  |
|       |              | L            | -            | н              | L              |             | Forward  |
|       | L            | -            | -            | L              | L              |             | Brake    |

- : denotes a don't care value. Z: High-Impedance

• In the standby mode, current consumption vanishes.

\* All power transistors turn off and the motor stops driving when the IC is detected in low voltage or thermal protection mode.

| Pin No.                          | Pin name                               | Description  | Equivalent circuit   |
|----------------------------------|--|--|--|
| 20<br>21                         | C1H<br>VG                              | Step-up capacitor connection pin.  | C1H  |
| 17                               | EXTRA                                  | Extra logic pin.<br>(Logic switch for PWM)   | EXTRA  |
| 16<br>12<br>15<br>14<br>11<br>10 | EN1<br>EN2<br>IN1<br>IN2<br>IN3<br>IN4 | Driver output switching.<br>Logic enable pin.<br>(Pull-down resistor incorporated) | Vcc  |
| 1<br>2<br>5<br>6                 | OUT1<br>OUT2<br>OUT3<br>OUT4           | Driver output.   | OUT<br>OUT<br>OUT<br>OUT<br>OUT<br>OUT<br>OUT<br>OUT<br>OUT<br>OUT |
| 8, 9,<br>22, 23                  | VM                                     | Motor block power supply.  |  |
| 13                               | VCC                                    | Logic block power supply.  |  |
| 18                               | SGND                                   | Control block ground.  |  |
| 3, 4                             | PGND                                   | Driver block ground.   |  |

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